

2823

Attorney Docket No. 0756-2228

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Hongyong ZHANG et al.

Serial No. 09/726,337

Filed: December 1, 2000

For: A SEMICONDUCTOR DEVICE

HAVING CHANNEL FORMATION

REGION COMPRISING SILICON

AND CONTAINING GROUP IV

ELEMENT

) Group Art Unit: 2823

) Examiner: W. Coleman

) CERTIFICATE OF MAILING

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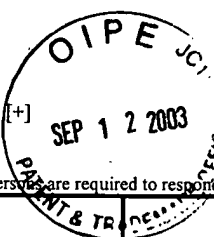
In accordance with the provisions of 37 C.F.R. 1.56 and 37 C.F.R. 1.97-1.99, Applicant submits herewith a Form PTO-1449 listing references known to Applicant and requests that these references be made of record in the above identified application. Copies of the references listed are submitted herewith in accordance with 37 C.F.R. 1.98(a).

JP 04-305940; JP 05-109737, and JP 04-337626 were submitted without Abstracts with the Information Disclosure Statement filed on August 25, 2003. Abstracts of each of these references are submitted herewith.

This Information Disclosure Statement is being submitted before the issuance of a first Office Action on the merits, therefore, no fee is required.

The Commissioner is hereby authorized to charge fees under 37 C.F.R. §§1.16, 1.17, 1.20(a), 1.20(b), 1.20(c), and 1.20(d) (except the Issue Fee) which may be required now or hereafter, or credit any overpayment to Deposit Account No. 50-2280.

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>		Application Number	09/726,337
		Filing Date	December 1, 2000
		First Named Inventor	Hongyong ZHANG et al.
		Group Art Unit	2823
		Examiner Name	W. Coleman
Sheet 1 of 1	Attorney Docket Number	0756-2228	

U.S. PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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FOREIGN PATENT DOCUMENTS								
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		Office ³	Number ⁴	Kind Code ⁵ (if known)				
		JP	04-305940			10/28/1992		AB
		JP	05-109737			04/30/1993		AB
		JP	04-337626			11/25/1992		AB
		JP	01-125866			05/18/1989		AB
		JP	02-098143			04/10/1990		AB
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		JP	57-102067			06/24/1982		AB
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		JP	62-174973			07/31/1987		AB
		JP	63-204769			08/24/1988		AB
		EP	0 251 767			01/07/1988		ENG

OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS			
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		Y. Kawazu et al., <i>Low-Temperature Crystallization of Hydrogenated Amorphous Silicon Induced by Nickel Silicide Formation</i> , Japanese Journal of Applied Physics, Vol. 29, No. 12, December, 1990, pp. 2698-2704.	

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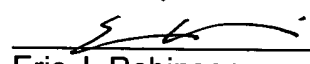
¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

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Respectfully submitted,



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